Micronics

New Product Release



High Power RF Amplifiers

Specifications

Frequency Range: 700Mhz to 2.1Ghz

Frequency modulation types: GSM, WCDMA and CW

Gain: Typical 43dB

Power Output: 20 Watts, @ 1dB point

Built in Amplifier Safeguards

- o VSWR protection with fault indicator when excessive power is reflected
- Metering: Forward and reflected power metering via analog voltage of 1-5VDC
- o Temperature: Monitors heat sink temperature with over temperature shut down with fault indicator.
- o Power: Exceeding maximum power will cause the amplifier to shut down
- Automatic Level Control: Feedback control loop maintains constant output level, can be user disabled
- o Gain control: 0-5VDC analog gain control
- Mute control: Reduces power to a low level so that it is safe for switching applications
- o Input overdrive protection: reduces drive to power amplifier when input level exceeds limits
- No input: low gain mode to prevent amplifier over-drive when input power is restored, with indicator

Operating Voltage: 28 volts+/- 1VDC

Operating Temperature: 0-50° C

• Input and Output VSWR: 1.5:1

Mechanical size: typical is 3.4"*8.4"*1"

Connector type: SMA

Efficiency: >30%

Non-Hermetic: Standard packaging

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